

# FZT788BTA Datasheet

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DiGi Electronics Part Number	FZT788BTA-DG
Manufacturer	<a href="#">Diodes Incorporated</a>
Manufacturer Product Number	FZT788BTA
Description	TRANS PNP 15V 3A SOT223-3
Detailed Description	Bipolar (BJT) Transistor PNP 15 V 3 A 100MHz 2 W S urface Mount SOT-223-3



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## Purchase and inquiry

Manufacturer Product Number:

FZT788BTA

Series:

-

Transistor Type:

PNP

Voltage - Collector Emitter Breakdown (Max):

15 V

Current - Collector Cutoff (Max):

100nA (ICBO)

Power - Max:

2 W

Operating Temperature:

-55°C ~ 150°C (TJ)

Package / Case:

TO-261-4, TO-261AA

Base Product Number:

FZT788

Manufacturer:

Diodes Incorporated

Product Status:

Active

Current - Collector (Ic) (Max):

3 A

Vce Saturation (Max) @ Ib, Ic:

500mV @ 50mA, 3A

DC Current Gain (hFE) (Min) @ Ic, Vce:

500 @ 10mA, 2V

Frequency - Transition:

100MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SOT-223-3

## Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.29.0075

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99



## 15V PNP MEDIUM POWER HIGH GAIN TRANSISTOR IN SOT223

## Features

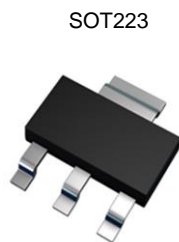
- $BV_{CEO} > -15V$
- $BV_{CBO} > -15V$
- $I_C = -3A$  High Continuous Current
- $h_{FE} > 300$  @  $-2A$  and Low Saturation Voltage
- Extremely Low Equivalent On-Resistance  $R_{CE(sat)}$  93m $\Omega$  at  $-3A$
- Complementary NPN Type: DIODES™ FZT688B
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](mailto:contact@diodes.com) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>**

## Mechanical Data

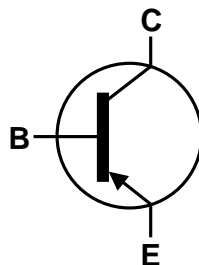
- Package: SOT223
- Package Material: Molded Plastic, "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.112 grams (Approximate)

## Applications

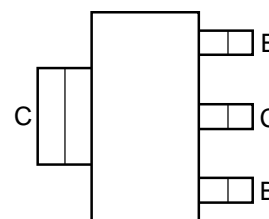
- Flash Gun Convertors
- Battery Powered Circuits



Top View



Device Symbol

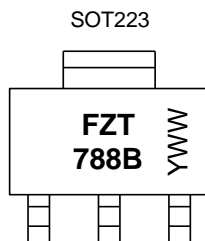
Top View  
Pin-Out

## Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT788BTA	Standard	FZT788B	7	12	1,000
FZT788BTC	Standard	FZT788B	13	12	2,500

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information



FZT 788B = Product Type Marking Code  
 YWW = Date Code Marking  
 Y or  $\bar{Y}$  = Last Digit of Year (ex: 5= 2015)  
 WW or  $\bar{W}W$  = Week Code (01~53)



FZT788B

**Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-15	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-15	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	I <sub>C</sub>	-3	A
Peak Pulse Current	I <sub>CM</sub>	-8	A

**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	P <sub>D</sub>	(Note 5)	3
		(Note 6)	2
		(Note 7)	1.6
		(Note 8)	1.2
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	(Note 5)	41.7
		(Note 6)	62.5
		(Note 7)	78.1
		(Note 8)	104
Thermal Resistance Junction to Lead	R <sub>θJL</sub>	12.9	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

**ESD Ratings** (Note 10)

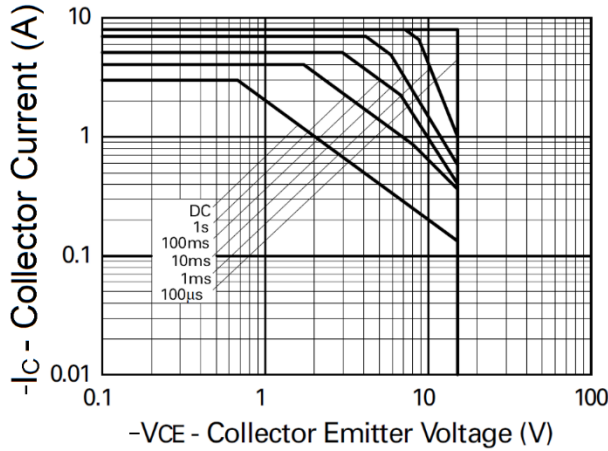
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
- For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
  - Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
  - Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
  - Same as Note 5, except the device is mounted on minimum recommended pad layout.
  - Thermal resistance from junction to solder-point (at the end of the collector lead).
  - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

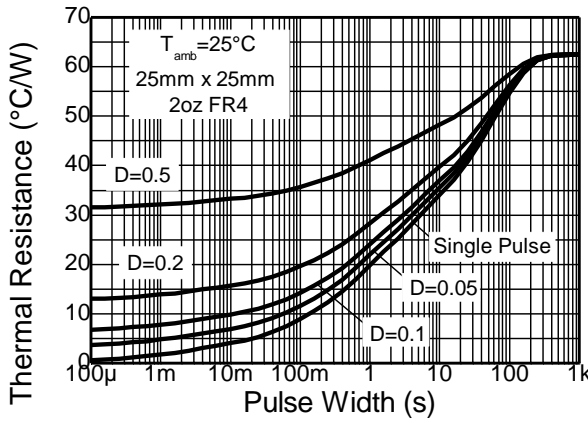


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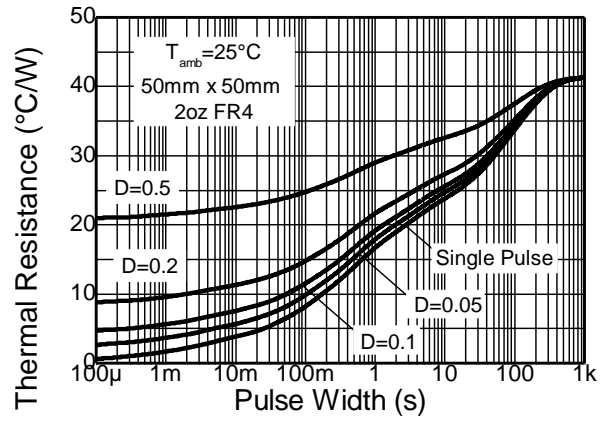
**Thermal Characteristics and Derating Information**



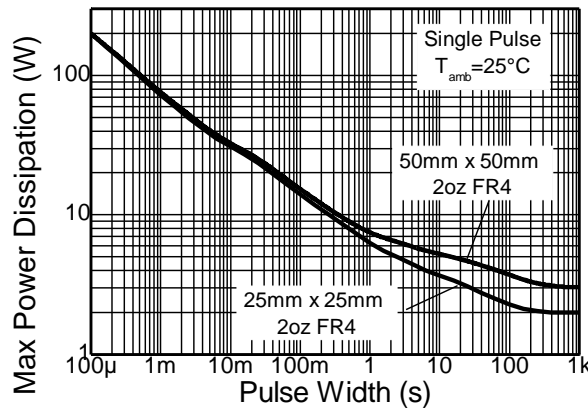
**Safe Operating Area**



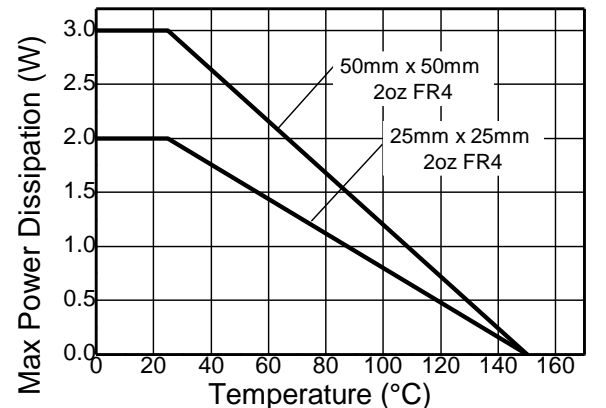
**Transient Thermal Impedance**



**Transient Thermal Impedance**



**Pulse Power Dissipation**



**Derating Curve**



FZT788B

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

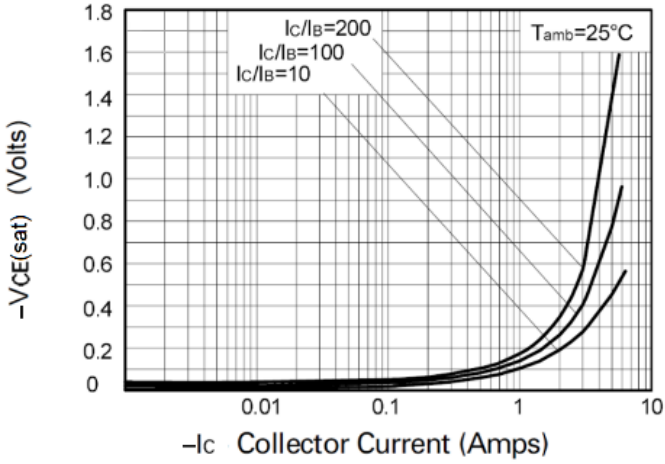
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_{CBO}$	-15	—	—	V	$I_C = -100\mu A$
Collector-Emitter Breakdown Voltage (Note 11)	$BV_{CEO}$	-15	—	—	V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	-7	—	—	V	$I_E = -100\mu A$
Collector-Base Cut-Off Current	$I_{CBO}$	—	—	-100	nA	$V_{CB} = -10V$
Emitter Cut-Off Current	$I_{EBO}$	—	—	-100	nA	$V_{EB} = -4V$
DC Current Gain (Note 11)	$h_{FE}$	500 400 300 150	— — — —	— — — —	—	$I_C = -10mA, V_{CE} = -2V$ $I_C = -1A, V_{CE} = -2V$ $I_C = -2A, V_{CE} = -2V$ $I_C = -6A, V_{CE} = -2V$
Collector-Emitter Saturation Voltage (Note 11)	$V_{CE(sat)}$	— — — —	— — — —	-0.15 -0.25 -0.45 -0.5	V	$I_C = -0.5A, I_B = -2.5mA$ $I_C = -1A, I_B = -5mA$ $I_C = -2A, I_B = -10mA$ $I_C = -3A, I_B = -50mA$
Base-Emitter Saturation Voltage (Note 11)	$V_{BE(sat)}$	—	—	-0.9	V	$I_C = -1A, I_B = -5mA$
Base-Emitter Turn-On Voltage (Note 11)	$V_{BE(on)}$	—	-0.75	—	V	$I_C = -1A, V_{CE} = -2V$
Input Capacitance	$C_{ibo}$	—	225	—	pF	$V_{EB} = -0.5V, f = 1MHz$
Output Capacitance	$C_{obo}$	—	25	—	pF	$V_{CB} = -10V, f = 1MHz$
Current Gain-Bandwidth Product	$f_T$	100	—	—	MHz	$V_{CE} = -5V, I_C = -50mA, f = 50MHz$
Turn-On Time	$t_{on}$	—	35	—	ns	$V_{CC} = -10V, I_C = -500mA$
Turn-Off Time	$t_{off}$	—	400	—	ns	$I_{B1} = -I_{B2} = -50mA$

Note: 11. Measured under pulsed conditions. Pulse width  $\leq 300 \mu s$ . Duty cycle  $\leq 2\%$ .

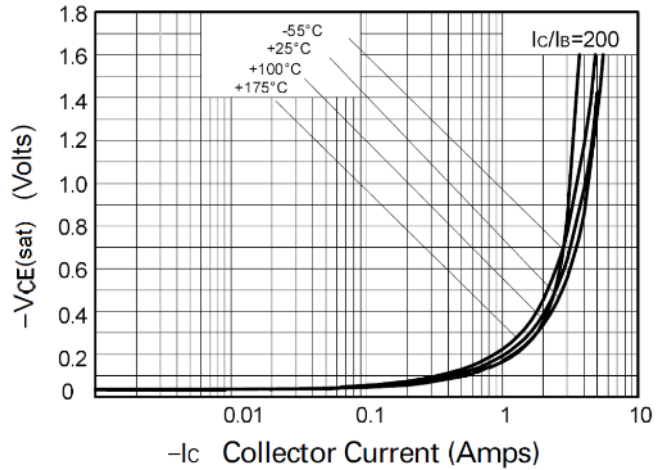


**FZT788B**

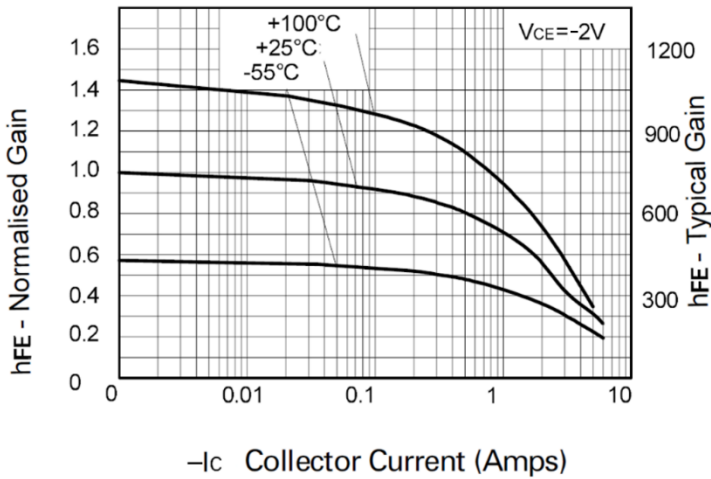
**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



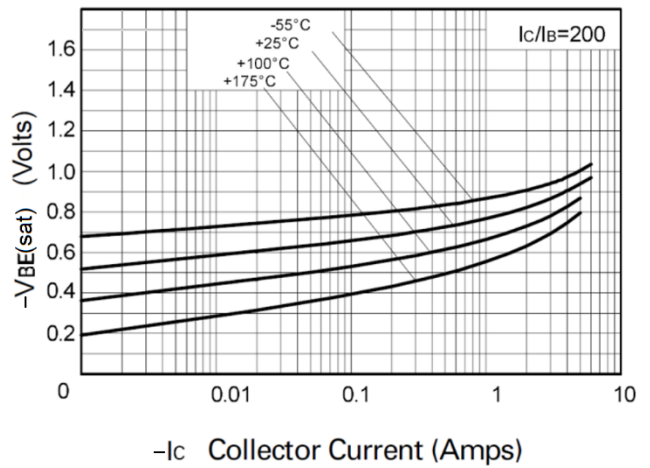
**VCE(sat) v IC**



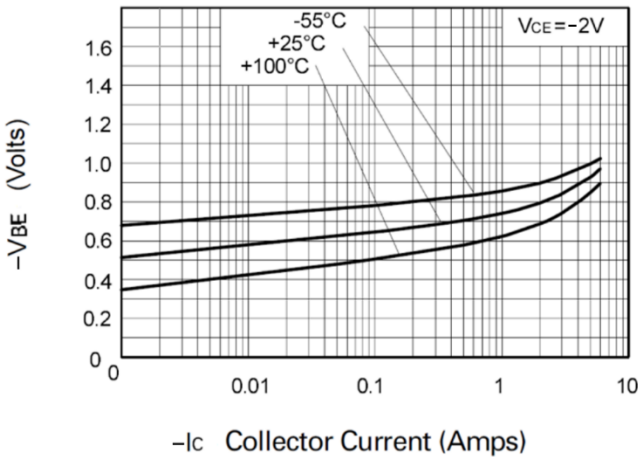
**VCE(sat) v IC**



**hFE v IC**



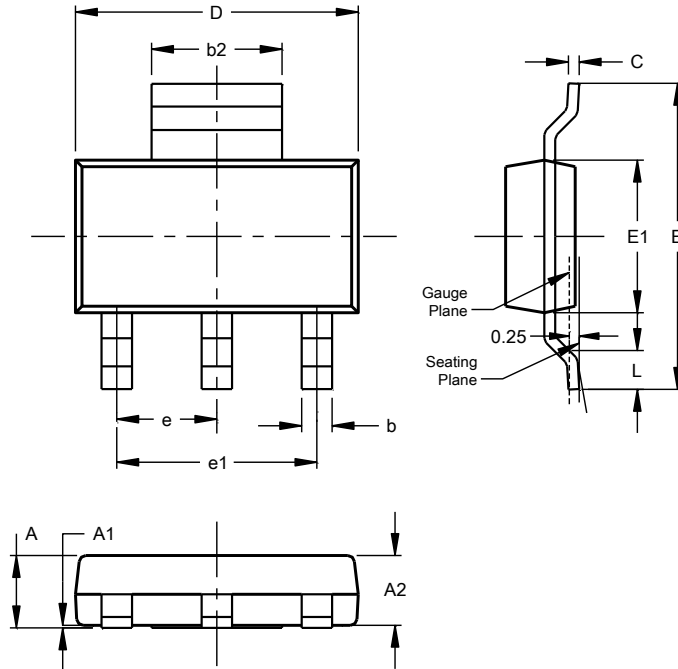
**VBE(sat) v IC**



**VBE(on) v IC**

## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

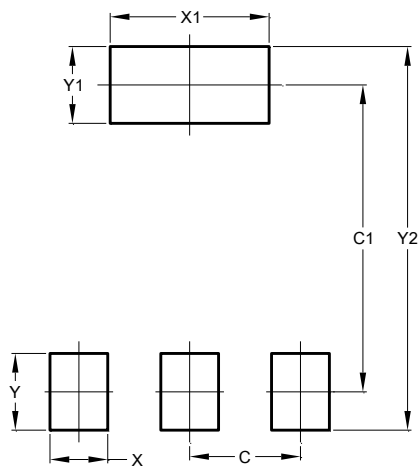


SOT223 (Type DN)			
Dim	Min	Max	Typ
A	--	1.70	--
A1	0.01	0.15	--
A2	1.50	1.68	1.60
b	0.60	0.80	0.70
b2	2.90	3.10	--
c	0.20	0.32	--
D	6.30	6.70	--
E	6.70	7.30	--
E1	3.30	3.70	--
e	--	--	2.30
e1	--	--	4.60
L	0.85	--	--
All Dimensions in mm			

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00





FZT788B

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